## Supplementary information for

## Time-dependent mechanical-electrical coupled behavior in single crystal ZnO nanorods

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Since it is possible that top and bottom of nanorods can be short-circuited by deposited metal layer on the side surface of nanorods, EDS analysis were performed for the ZnO nanorod at the location marked in Fig. S1a. As shown in Fig. S1b, metal components of Au and Ti were found only on the top surface of nanorod, while any metals were detected on its side surface (see Fig. S1c).



Fig. S1. (a) SEM image of metal-deposited ZnO nanorods. EDS results obtained from (b) top surface of nanorod and (c) its side surface.

In addition, the resistivity ( $\rho = RA/l$ ) of the nanorod is calculated to be ~  $1.2 \times 10^{-3}$  and  $0.8 \times 10^{-3} \Omega \cdot m$  from method 1 and 2 as shown in Tabe S1, which is again comparable with the values in the literatures of ~ $10^{-4}$ - $10^{-1} \Omega \cdot m$  for ZnO nanomaterials [S1].

	$R_{\rm NR}$ [k $\Omega$ ]	<i>d</i> [µm]	<i>l</i> [μm]	<i>ρ</i> [Ω·m]
Method 1	1.609	2.1	3.7	1.246×10 <sup>-3</sup>
Method 2	1.0958			0.848×10 <sup>-3</sup>

Table S1. Calculation of ZnO nanorod resistivity

Based on the evidences described above and included in the manuscript, the electrical responses we measured is resulted from the ZnO nanorods rather than short-circuited Au layer on the surface of nanorod.

## References

[S1] J. He et al., J. Am. Chem. Soc., 127 (2005) 16376.